

ZTX415STZ Datasheet



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DiGi Electronics Part Number ZTX415STZ-DG

Manufacturer Diodes Incorporated

Manufacturer Product Number ZTX415STZ

Description TRANS NPN 100V 0.5A E-LINE

Detailed Description Bipolar (BJT) Transistor NPN - Avalanche Mode 100 V 500 mA 40MHz 680 mW Through Hole E-Line (TO

-92 compatible)



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
ZTX415STZ	Diodes Incorporated
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN - Avalanche Mode	500 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
100 V	500mV @ 1mA, 10mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100nA (ICBO)	25 @ 10mA, 10V
Power - Max:	Frequency - Transition:
680 mW	40MHz
Operating Temperature:	Mounting Type:
-55°C ~ 175°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
E-Line-3, Formed Leads	E-Line (TO-92 compatible)
Base Product Number:	
ZTX415	

Environmental & Export classification

8541.21.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	





NPN SILICON PLANAR MEDIUM POWER TRANSISTOR

Features

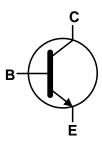
- Avalanche Transistor
- 60A Peak Avalanche Current (Pulse Width = 20ns)
- BV_{CES} > 260V
- BV_{CEO} > 100V
- Specifically Designed for Avalanche Mode Operation
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

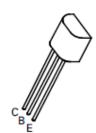
- Case: E-Line
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 159mg (Approximate)







Device Symbol



Top View Pin-Out

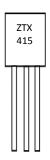
Ordering Information (Note 4)

Part Number	Compliance	Marking	Quantity
ZTX415	Standard	ZTX415	4000 Bulk
ZTX415STZ	Standard	ZTX415	2000 Taped

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



ZTX 415 = Product Type Marking Code



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	260	V
Collector-Emitter Voltage	V _{CES}	260	V
Collector-Emitter Voltage	V _{CEO}	100	V
Emitter-Base Voltage	V _{EBO}	6	V
Continuous Collector Current	lc	500	mA
Peak Collector Current (Pulse Width = 20ns)	I _{CM}	60	А

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_{D}	680	mW
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	250	°C/W
Thermal Resistance, Junction to Lead	(Note 6)	$R_{ heta JL}$	197	°C/W
Operating and Storage Temperature Range		$T_{J_1}T_{STG}$	-55 to +150	°C

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air
- conditions whilst operating in a steady-state.
 6. Thermal resistance from junction to solder-point (at the end of the collector lead).
 7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

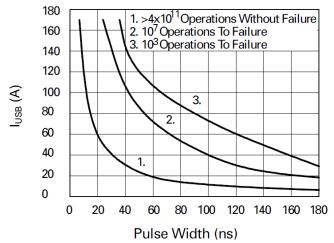
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV _{CES}	260	_	-	V	I _C = 1mA T _J = -55 to +150°C
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	100	_	_	V	I _C = 100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	6	_	-	V	I _E = 100μA
Collector Cutoff Current	I _{CBO}	_	_	100 10	nΑ μΑ	V _{CB} = 180V V _{CB} = 180V, T _J = +100°C
Emitter Cutoff Current	I _{EBO}	_	_	100	nA	V _{EB} = 4V
Static Forward Current Transfer Ratio (Note 8)	h _{FE}	25	_	_	_	I _C = 10mA, V _{CE} = 10V
Collector-Emitter Saturation Voltage (Note 8)	V _{CE(sat)}	_	_	500	mV	$I_C = 10mA$, $I_B = 1mA$
Base-Emitter Saturation Voltage (Note 8)	V _{BE(sat)}	_	_	900	mV	$I_C = 10mA$, $I_B = 1mA$
Pulsed Current in Second Breakdown	I _{USB}		25 35		A A	$V_C = 200V, C_{CE} = 620pF$ $V_C = 250V, C_{CE} = 620pF$
Collector-Emitter inductance	L _{ce}	_	2.5	_	nΗ	Standard SOT23 Leads
Output Capacitance	C _{obo}	_		8	pF	$V_{CB} = 20V$, $I_E = 0$ f = 100MHz
Transition Frequency	f⊤	40	_		MHz	$V_{CE} = 20V$, $I_C = 10mA$, $f = 20MHz$

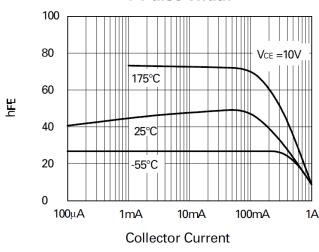
Note: 8. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



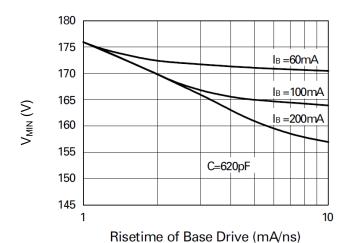
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



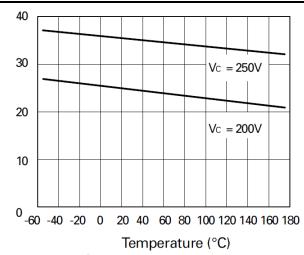
Maximum Avalanche Current v Pulse Width



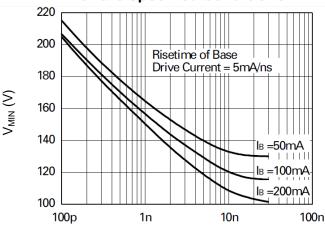
hFE v IC



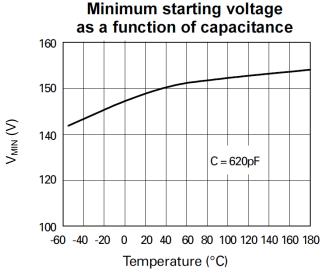
Minimum starting voltage as a function of drive current



I_{USB} v Temperature for the specified conditions



Collector-Emitter Capacitance (F)



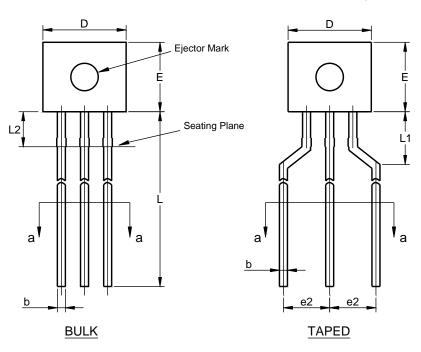
Minimum starting voltage as a function of temperature



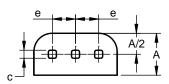
Package Outline Dimensions

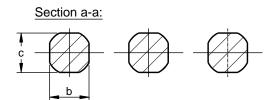
Please see http://www.diodes.com/package-outlines.html for the latest version.

E-Line



E-Line					
Dim	Min	Max	Тур		
Α	2.16	2.41	2.28		
b	0.41	0.49	0.44		
С	0.41	0.49	0.44		
D	4.37	4.77	4.57		
Е	3.61	4.01	3.90		
е	1.27 REF				
e2	e2 2.54 REF				
L	13.00	13.97	13.50		
L1	2.50	3.50			
L2			2.50		
All Dimensions in mm					

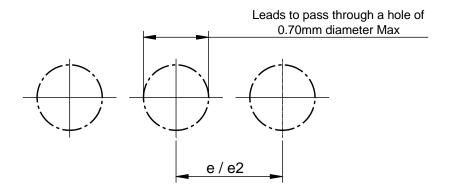




Suggested Pad Hole

Please see http://www.diodes.com/package-outlines.html for the latest version.

E-Line





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